

Silicon Capacitance Diodes

Germanium Diodes

Silicon Epitaxial Planar Capacitance Diode in DO-7 glass package with wide effective capacitance variation for tuning over the total frequency range in short-wave, medium-wave, and long-wave circuits

Type	Characteristics and maximum ratings at $T_{amb} = 25^\circ\text{C}$									
	$\bar{V}_R = 0 \dots 1,5\text{ V}$	$\bar{V}_R = 1\text{ V}$	$\bar{V}_R = 4 \dots 10\text{ V}$	$\bar{V}_R = 0 \dots 10\text{ V}$	$\bar{V}_R = 1 \dots 10\text{ V}$	$\bar{V}_R = 1\text{ V}$	$\bar{V}_R = 1\text{ V}$ $f = 0,15 \dots 0,5\text{ MHz}$	$\bar{V}_R = 10\text{ V}$ $f = 0,3 \dots 1,5\text{ MHz}$		$\bar{V}_R = 10\text{ V}$
	$C_{tot}\text{ pF}$	$C_{tot}\text{ pF}$	$C_{tot}\text{ pF}$	$C_{tot}(0\text{ V})$ $C_{tot}(10\text{ V})$	$C_{tot}(1\text{ V})$ $C_{tot}(10\text{ V})$	$r_s\ \Omega$	Q	Q	$V_{(BR)R}\text{ V}$	$I_R\ \mu\text{A}$
BA 163	260	> 180	10	35 (> 26)	25 (> 18)	1,5	500 (> 200)	500 (> 200)	> 14	< 0,5

The BA 163 is available in matched sets of two or more units. For matching see data sheets.

Silicon Epitaxial Planar Bandswitching Diodes in "double-plug" glass package.
For use in radio and TV tuners.

Type	Maximum Ratings		Characteristics at $T_{amb} = 25^\circ\text{C}$						
	@ $T_{amb} = 60^\circ\text{C}$		@ $I_F = 100\text{ mA}$	@ $\bar{V}_R = 15\text{ V}$		@ $I_F = 10\text{ mA}$ $f = 50 \dots 1000\text{ MHz}$	$I_F = 2 \dots 40\text{ mA}$	@ $\bar{V}_R = 15\text{ V}$ $f = 50 \dots 1000\text{ MHz}$	
	$V_R\text{ V}$	$I_F\text{ mA}$	$T_j\text{ }^\circ\text{C}$	$V_F\text{ V}$	$I_R\text{ nA}$	$L_s\text{ nH}$	$r_F\ \Omega$	$\Delta r_F\ \%/mA$	$C_{tot}\text{ pF}$
BA 243	20	100	100	< 1	< 100	2,5	0,7 (< 1)	5	< 2
BA 244	20	100	100	< 1	< 100	2,5	0,4 (< 0,5)	5	< 2

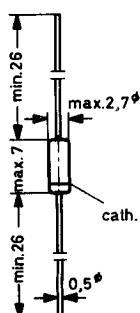
BA 243: black cathode band; BA 244: green cathode band.

Germanium Gold Bonded Diodes in DO-7 glass package

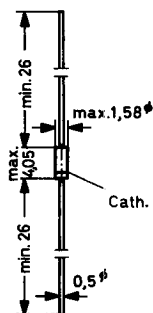
Type	Maximum Ratings			Characteristics at $T_{amb} = 25^\circ\text{C}$					
	$T_{amb} = 25^\circ\text{C}$			$T_{amb} = 25^\circ\text{C}$					
	$V_R\text{ V}$	$I_0\text{ mA}$	$P_{tot}\text{ mW}$	$T_j\text{ }^\circ\text{C}$	$I_R\ \mu\text{A}$	@ $V_R\text{ V}$	$V_F\text{ V}$	@ $I_F\text{ mA}$	$t_{rr}\text{ ns or }Q_s$
AA 143	25	60	80	85	< 20	20	0,29 ... 0,33	2	—
AA 144	90	10	80	85	< 200	75	0,36 (< 1)	5	—
DK 13	50	120	—	75	< 60	50	0,3 ... 0,4	3	$Q_s = 700\text{ pC max}$
DK 14	80	120	—	75	< 90	80	0,35 ... 0,4	3	$Q_s = 700\text{ pC max}$
DK 15	100	120	—	75	< 90	100	0,35 ... 0,4	3	$Q_s = 700\text{ pC max}$
DK 19	25	110	—	75	< 160 ¹	25	0,2 ... 0,33	1	$Q_s = 600\text{ pC max}$
DK 20	50	70	—	90	< 25	50	0,8	100	500 $I_F = 10\text{ mA}, V_R = 10\text{ V}, I_R = 1\text{ mA}$
DK 21	8	30	—	75	< 25	3	0,32	1	$Q_s = 350\text{ pC}$

¹At 60°C

DO-7 Outline
Weight 0,2 p



Double-plug Outline
Weight 0,1 p.



Dimensions in mm